# **RENESAS** 1:2, Differential-to-LVCMOS/LVTTL Zero Delay Clock Generator

# 87002-02

## DATA SHEET

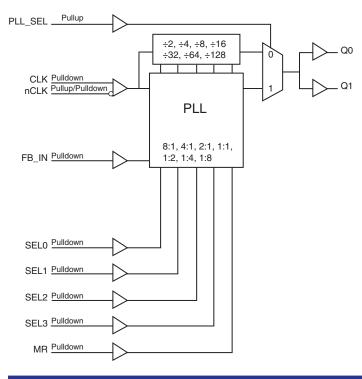
## **General Description**

The 87002-02 is a highly versatile 1:2 Differential-to-LVCMOS/LVTTL Clock Generator. The 87002-02 has a differential clock input. The CLK, nCLK pair can accept most standard differential input levels. Internal bias on the nCLK input allows the CLK input to accept LVCMOS/LVTTL. The 87002-02 has a fully integrated PLL and can be configured as zero delay buffer, multiplier or divider and has an input and output frequency range of 15.625MHz to 250MHz. The reference divider, feedback divider and output divider are each programmable, thereby allowing for the following output-to-input frequency ratios: 8:1, 4:1, 2:1, 1:1, 1:2, 1:4, 1:8. The external feedback allows the device to achieve "zero delay" between the input clock and the output clocks. The PLL\_SEL pin can be used to bypass the PLL for system test and debug purposes. In bypass mode, the reference clock is routed around the PLL and into the internal output dividers.

## **Features**

- Two LVCMOS/LVTTL outputs,  $7\Omega$  typical output impedance
- CLK, nCLK pair can accept the following differential input levels: LVPECL, LVDS, HSTL, HCSL, SSTL
- Internal bias on nCLK to support LVCMOS/LVTTL levels on CLK input
- Output frequency range: 15.625MHz to 250MHz
- Input frequency range: 15.625MHz to 250MHz
- VCO range: 250MHz to 500MHz
- External feedback for "zero delay" clock regeneration with configurable frequencies
- Programmable dividers allow for the following output-to-input frequency ratios: 8:1, 4:1, 2:1, 1:1, 1:2, 1:4, 1:8
- Fully integrated PLL
- Cycle-to-cycle jitter: 45ps (maximum)
- Output skew: 35ps (maximum)
- Static phase offset: -10ps ± 150ps (3.3V ± 5%)
- Full 3.3V or 2.5V operating supply
- 5V tolerant inputs
- 0°C to 70°C ambient operating temperature
- Available in lead-free (RoHS 6) package
- Industrial temperature information available upon request

# **Block Diagram**



# **Pin Assignment**

			-
GND□	1	20	VDDO
Q0 🗆	2	19	_Q1
V <sub>DDO</sub>	3	18	GND
SEL0	4	17	
SEL1	5	16	□nc
SEL2	6	15	□ MR
SEL3	7	14	□FB_IN
Vdd	8	13	PLL_SEL
CLK	9	12	<b>V</b> DDA
nCLK	10	11	GND

87002-02

20-Lead TSSOP 6.50mm x 4.40mm x 0.925mm package body G Package Top View

# Table 1. Pin Descriptions

Number	Name	Т	уре	Description
1, 11, 18	GND	Power		Power supply ground.
2, 19	Q0, Q1	Output		Single-ended clock outputs. $7\Omega$ typical output impedance. LVCMOS/LVTTL interface levels.
3, 17, 20	V <sub>DDO</sub>	Power		Output supply pins.
4, 5, 6, 7	SEL0, SEL1, SEL2, SEL3	Input	Pulldown	Determines output divider values in Table 3. LVCMOS / LVTTL interface levels.
8	V <sub>DD</sub>	Power		Core supply pin.
9	CLK	Input	Pulldown	Non-inverting differential clock input.
10	nCLK	Input	Pullup/ Pulldown	Inverting differential clock input. V <sub>DD</sub> /2 default when left floating.
12	V <sub>DDA</sub>	Power		Analog supply pin.
13	PLL_SEL	Input	Pullup	PLL select. Selects between the PLL and reference clock as the input to the dividers. When LOW, selects reference clock (PLL Bypass). When HIGH, selects PLL (PLL enabled). LVCMOS/LVTTL interface levels.
14	FB_IN	Input	Pulldown	Feedback input to phase detector for regenerating clocks with "Zero Delay." Connect to one of the outputs. LVCMOS/LVTTL interface levels.
15	MR	Input	Pulldown	Active HIGH Master Reset. When logic HIGH, the internal dividers are reset causing the outputs to go low. When logic LOW, the internal dividers and the outputs are enabled. LVCMOS / LVTTL interface levels.
16	nc	Unused		No connect.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

# **Table 2. Pin Characteristics**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ
<u> </u>	Power Dissipation	$V_{DD}$ , $V_{DDA}$ , $V_{DDO} = 3.465 V$			23	pF
C <sub>PD</sub>	Capacitance (per output)	$V_{DD}$ , $V_{DDA}$ , $V_{DDO} = 2.625V$			17	pF
R <sub>OUT</sub>	Output Impedance		5	7	12	Ω

# **Function Tables**

Table 3A. PLL Enable Function Table

			Inputs		Outputs PLL_SEL = 1 PLL Enable Mode
SEL3	SEL2	SEL1	SEL0	Reference Frequency Range (MHz)	Q0, Q1
0	0	0	0	125 - 250	÷1
0	0	0	1	62.5 - 125	÷1
0	0	1	0	31.25 - 62.5	÷1
0	0	1	1	15.625 - 31.25	÷1
0	1	0	0	125 - 250	÷2
0	1	0	1	62.5 - 125	÷2
0	1	1	0	31.25 - 62.5	÷2
0	1	1	1	125 - 250	÷4
1	0	0	0	62.5 - 125	÷4
1	0	0	1	125 - 250	÷8
1	0	1	0	62.5 - 125	x2
1	0	1	1	31.25 - 62.5	x2
1	1	0	0	15.625 - 31.25	x2
1	1	0	1	31.25 - 62.5	x4
1	1	1	0	15.625 - 31.25	x4
1	1	1	1	15.625 - 31.25	x8

## Table 3B. PLL Bypass Function Table

	Inp	Outputs PLL_SEL = 0 PLL Bypass Mode		
SEL3	SEL2	SEL1	SEL0	Q0, Q1
0	0	0	0	÷8
0	0	0	1	÷8
0	0	1	0	÷8
0	0	1	1	÷16
0	1	0	0	÷16
0	1	0	1	÷16
0	1	1	0	÷32
0	1	1	1	÷32
1	0	0	0	÷64
1	0	0	1	÷128
1	0	1	0	÷4
1	0	1	1	÷4
1	1	0	0	÷8
1	1	0	1	÷2
1	1	1	0	÷4
1	1	1	1	÷2

# **Absolute Maximum Ratings**

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics or AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V <sub>DD</sub>	4.6V
Inputs, V <sub>I</sub>	-0.5V to V <sub>DD</sub> + 0.5V
Outputs, V <sub>O</sub>	-0.5V to V <sub>DDO</sub> + 0.5V
Package Thermal Impedance, $\theta_{JA}$	73.2°C/W (0 lfpm)
Storage Temperature, T <sub>STG</sub>	-65°C to 150°C

# **DC Electrical Characteristics**

#### Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ , $T_A = 0^{\circ}C$ to $70^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Core Supply Voltage		3.135	3.3	3.465	V
V <sub>DDA</sub>	Analog Supply Voltage		3.135	3.3	3.465	V
V <sub>DDO</sub>	Output Supply Voltage		3.135	3.3	3.465	V
I <sub>DD</sub>	Power Supply Current				100	mA
I <sub>DDA</sub>	Analog Supply Current				16	mA
I <sub>DDO</sub>	Output Supply Current				6	mA

#### Table 4B. Power Supply DC Characteristics, $V_{DD} = V_{DDA} = V_{DDO} = 2.5V \pm 5\%$ , $T_A = 0^{\circ}C$ to $70^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Core Supply Voltage		2.375	2.5	2.625	V
V <sub>DDA</sub>	Analog Supply Voltage		2.375	2.5	2.625	V
V <sub>DDO</sub>	Output Supply Voltage		2.375	2.5	2.625	V
I <sub>DD</sub>	Power Supply Current				96	mA
I <sub>DDA</sub>	Analog Supply Current				15	mA
I <sub>DDO</sub>	Output Supply Current				6	mA

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
			V <sub>DD</sub> = 3.3V	2		V <sub>DD</sub> + 0.3	V
V <sub>IH</sub>	Input High Voltage		V <sub>DD</sub> = 2.5V	1.7		V <sub>DD</sub> + 0.3	V
V			V <sub>DD</sub> = 3.3V	-0.3		0.8	V
V <sub>IL</sub>	Input Low Voltage		V <sub>DD</sub> = 2.5V	-0.3		0.7	V
IIH	Input High Current	FB_IN, SEL[0:3], MR	$V_{DD} = V_{IN} = 3.465V \text{ or } 2.625V$			150	μA
		PLL_SEL	V <sub>DD</sub> = V <sub>IN</sub> = 3.465V or 2.625V			5	μA
	Input Low Current	FB_IN, SEL[0:3], MR	$V_{DD} = 3.465 V \text{ or } 2.625 V,$ $V_{IN} = 0 V$	-5			μA
I <sub>IL</sub>		PLL_SEL	$V_{DD} = 3.465 V \text{ or } 2.625 V,$ $V_{IN} = 0 V$	-150			μA
V			V <sub>DDO</sub> = 3.465V	2.6			V
V <sub>OH</sub>	Output High Voltage; NOTE 1		V <sub>DDO</sub> = 2.625V	1.8			V
V <sub>OL</sub>	Output Low Voltage; NOTE 1		V <sub>DDO</sub> = 3.465V or 2.625V			0.5	V

## Table 4C. LVCMOS/LVTTL DC Characteristics, $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ or 2.5V ± 5%, $T_A = 0^{\circ}C$ to 70°C

NOTE 1: Outputs terminated with 50  $\Omega$  to V<sub>DDO</sub>/2. In the Parameter Measurement Information Section, see *Output Load Test Circuit Diagrams*.

Table 4D. Differential DC Characteristics,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$  or 2.5V  $\pm 5\%$ ,  $T_A = 0^{\circ}C$  to 70°C to

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
1	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465 V \text{ or } 2.625 V$			150	μA
ΊΗ		nCLK	$V_{DD} = V_{IN} = 3.465 V \text{ or } 2.625 V$			150	μA
	Input Low Current	CLK	$V_{DD} = 3.465 V \text{ or } 2.625 V, V_{IN} = 0 V$	-5			μA
ιĽ		nCLK	$V_{DD} = 3.465V \text{ or } 2.625V, V_{IN} = 0V$	-150			μA
V <sub>PP</sub>	Peak-to-Peak Voltage	; NOTE 1		0.15		1.3	V
V <sub>CMR</sub>	Common Mode Input Voltage; NOTE 1, 2			GND + 0.5		V <sub>DD</sub> – 0.85	V

NOTE 1:  $V_{\rm IL}$  should not be less than -0.3V. NOTE 2: Common mode input voltage is defined as  $V_{\rm IH}.$ 

# **AC Electrical Characteristics**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Output Frequency		15.625		250	MHz
t <sub>PD</sub>	Propagation Delay; NOTE 1	PLL_SEL = 0V, $f \le 250MHz$ , Qx ÷ 2	4.8		5.8	ns
<i>t</i> (Ø)	Static Phase Offset; NOTE 2, 4	PLL_SEL = 3.3V, f <sub>REF</sub> ≤ 167MHz, Qx ÷ 1	-160	-10	140	ps
<i>t</i> sk(o)	Output Skew; NOTE 3, 4	PLL_SEL = 0V			40	ps
<i>t</i> jit(cc)	Cycle-to-Cycle Jitter; NOTE 4	f <sub>OUT</sub> > 40MHz			45	ps
tL	PLL Lock Time				1	ms
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%	400		800	ps
odc	Output Duty Cycle		40		60	%

Table 5A. AC Characteristics,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = 0^{\circ}C$  to  $70^{\circ}C$ 

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from the differential input crossing point to the output at V<sub>DDO</sub>/2.

NOTE 2: Defined as the time difference between the input reference clock and the average feedback input signal, when the PLL is locked and the input reference frequency is stable.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V<sub>DDO</sub>/2.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Output Frequency		15.625		250	MHz
t <sub>PD</sub>	Propagation Delay; NOTE 1	PLL_SEL = 0V, f $\leq$ 250MHz, Qx $\div$ 2	4.9		6.7	ns
t(Ø)	Static Phase Offset; NOTE 2, 4	PLL_SEL = 2.5V, f <sub>REF</sub> ≤ 167MHz, Qx ÷ 1	-240	-65	110	ps
<i>t</i> sk(o)	Output Skew; NOTE 3, 4	PLL_SEL = 0V			35	ps
<i>t</i> jit(cc)	Cycle-to-Cycle Jitter; NOTE 4	f <sub>OUT</sub> > 40MHz			45	ps
tL	PLL Lock Time				1	ms
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%	400		700	ps
odc	Output Duty Cycle		44		56	%

#### Table 5B. AC Characteristics, $V_{DD} = V_{DDA} = V_{DDO} = 2.5V \pm 5\%$ , $T_A = 0^{\circ}C$ to 70°C

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

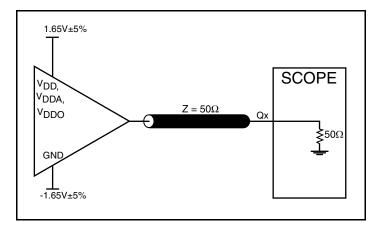
NOTE 1: Measured from the differential input crossing point to the output at V<sub>DDO</sub>/2.

NOTE 2: Defined as the time difference between the input reference clock and the average feedback input signal, when the PLL is locked and the input reference frequency is stable.

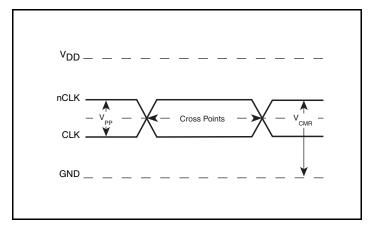
NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V<sub>DDO</sub>/2.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

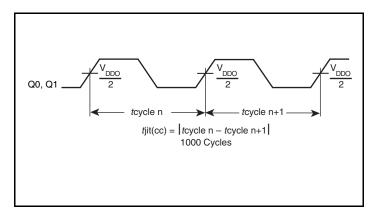
## **Parameter Measurement Information**



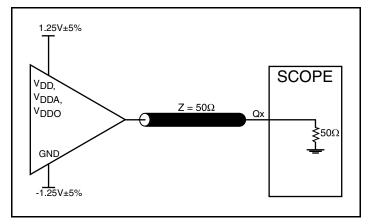
3.3V Output Load AC Test Circuit



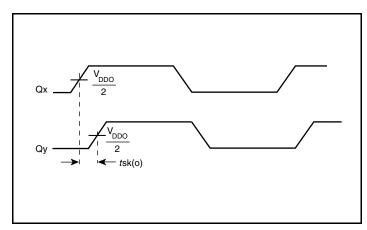
**Differential Input Level** 



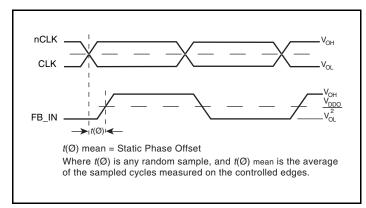
**Cycle-to-Cycle Jitter** 



2.5V Output Load AC Test Circuit



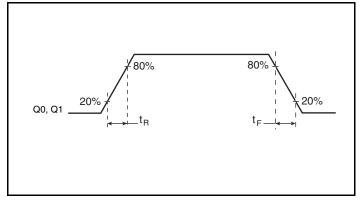
**Output Skew** 

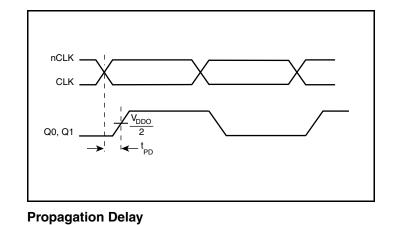


**Static Phase Offset** 

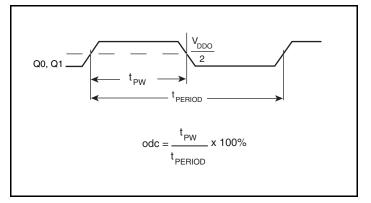
# RENESAS

## Parameter Measurement Information, continued





**Output Rise/Fall Time** 



**Output Duty Cycle/Pulse Width/Period** 

# **Applications Information**

## **Power Supply Filtering Technique**

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 87002-02 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD,}$   $V_{DDA}$  and  $V_{DDO}$  should be individually connected to the power supply plane through vias, and  $0.01\mu$ F bypass capacitors should be used for each pin. *Figure 1* illustrates this for a generic  $V_{DD}$  pin and also shows that  $V_{DDA}$  requires that an additional  $10\Omega$  resistor along with a  $10\mu$ F bypass capacitor be connected to the  $V_{DDA}$  pin. The  $10\Omega$  resistor can also be replaced by a ferrite bead.

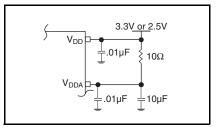


Figure 1. Power Supply Filtering

## Wiring the Differential Input to Accept Single-Ended Levels

*Figure 2* shows how a differential input can be wired to accept single ended levels. The reference voltage  $V_{REF} = V_{CC}/2$  is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the  $V_{REF}$  in the center of the input voltage swing. For example, if the input clock swing is 2.5V and  $V_{CC} = 3.3V$ , R1 and R2 value should be adjusted to set  $V_{REF}$  at 1.25V. The values below are for when both the single ended swing and  $V_{CC}$  are at the same voltage. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission line impedance. For most 50 $\Omega$  applications, R3 and R4 can be 100 $\Omega$ . The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the differential input can handle full rail LVCMOS signaling, it is recommended that the amplitude be reduced. The datasheet specifies a lower differential amplitude, however this only applies to differential signals. For single-ended applications, the swing can be larger, however V<sub>IL</sub> cannot be less than -0.3V and V<sub>IH</sub> cannot be more than V<sub>CC</sub> + 0.3V. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

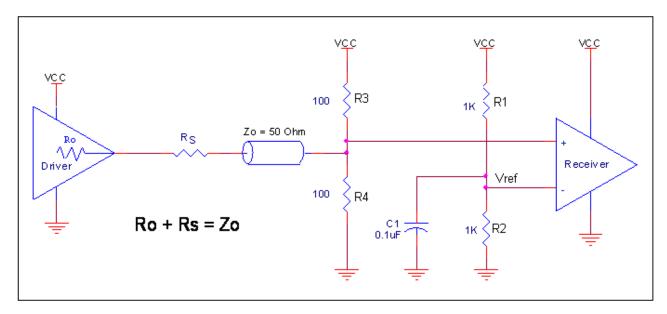


Figure 2. Recommended Schematic for Wiring a Differential Input to Accept Single-ended Levels

# **Differential Clock Input Interface**

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both differential signals must meet the V<sub>PP</sub> and V<sub>CMR</sub> input requirements. *Figures 3A to 3F* show interface examples for the CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only.

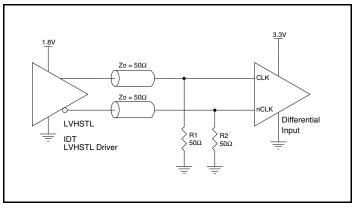


Figure 3A. CLK/nCLK Input Driven by an IDT Open Emitter LVHSTL Driver

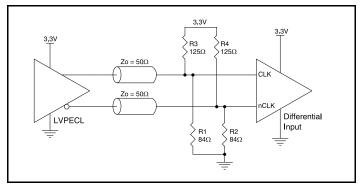
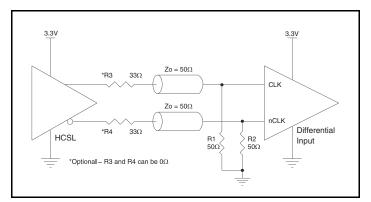


Figure 3C. CLK/nCLK Input Driven by a 3.3V LVPECL Driver





Please consult with the vendor of the driver component to confirm the driver termination requirements. For example, in Figure 3A, the input termination applies for IDT open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

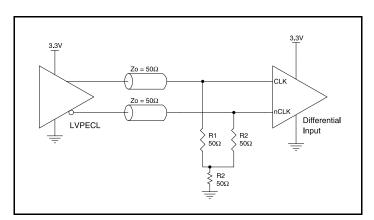


Figure 3B. CLK/nCLK Input Driven by a 3.3V LVPECL Driver

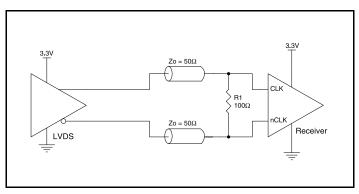


Figure 3D. CLK/nCLK Input Driven by a 3.3V LVDS Driver

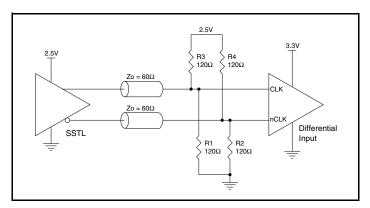


Figure 3F. CLK/nCLK Input Driven by a 2.5V SSTL Driver

## **Schematic Example**

*Figure 4* shows an example of 87002-02 application schematic. In this example, the device is operated at  $V_{DD}$  = 3.3V. The decoupling

capacitors should be located as close as possible to the power pin. The input is driven by a 3.3V LVPECL driver.

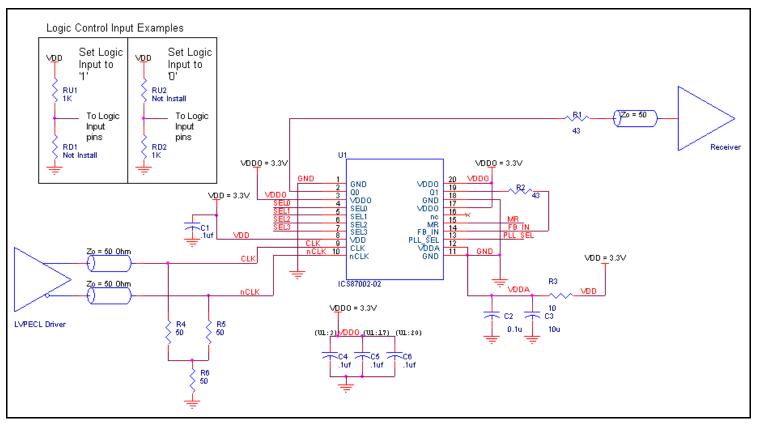


Figure 4. 87002-02 Schematic Example

#### **Recommendations for Unused Input and Output Pins**

#### Inputs:

#### **LVCMOS Control Pins**

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A  $1k\Omega$  resistor can be used.

#### **Outputs:**

#### **LVCMOS Outputs**

All unused LVCMOS output can be left floating. There should be no trace attached.

## **Reliability Information**

#### Table 6. $\theta_{\text{JA}}$ vs. Air Flow Table for a 20 Lead TSSOP

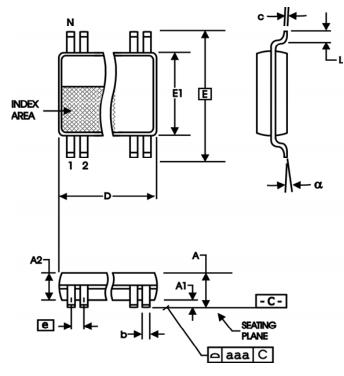
$ heta_{JA}$ vs. Air Flow					
Linear Feet per Minute	0	200	500		
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98.0°C/W	88.0°C/W		
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W		
NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.					

## **Transistor Count**

The transistor count for 87002-02 is: 2578

## Package Outline and Package Dimensions

#### Package Outline - G Suffix for 20 Lead TSSOP



#### Table 7. Package Dimensions

Table III ackage Dimensione					
All Dimensions in Millimeters					
Symbol	Minimum	Maximum			
N	20				
Α		1.20			
A1	0.05	0.15			
A2	0.80	1.05			
b	0.19	0.30			
С	0.09	0.20			
D	6.40	6.60			
E	6.40 Basic				
E1	4.30	4.50			
е	0.65 Basic				
L	0.45	0.75			
α	0°	8°			
aaa		0.10			

Reference Document: JEDEC Publication 95, MO-153



# **Ordering Information**

## Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
87002AG-02LF	ICS87002A02L	"Lead-Free" 20 Lead TSSOP	Tube	0°C to 70°C
87002AG-02LFT	ICS87002A02L	"Lead-Free" 20 Lead TSSOP	Tape & Reel	0°C to 70°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

# **Revision History Sheet**

Rev	Table	Page	Description of Change	
	T2	2	Pin Characteristics Table - added C <sub>PD</sub> specs.	
		10	Added Recommendations for Unused Input and Output Pins section.	
В		11	Updated Differential Clock Input Interface section.	4/29/08
		12	Added Schematic Layout	
	Т8	14	Ordering Information Table - added Lead-Free marking.	
	T5A, T5B	7	Added thermal note.	
С	T5B	7	2.5V AC Characteristics Table - due to datasheet conversion on April 29, 2008, corrected typo for static phase offset spec from -650 to -65.	8/9/10
C		10	Updated Wiring the Differential Levels to Accept Single-ended Levels section.	8/9/10
	Т8	14	Ordering Information Table - deleted "ICS" prefix from the Part/Order Number column. Updated header/footer of datasheet.	
			·	
С	Т8	14	Ordering Information - removed leaded devices. Updated data sheet format.	7/13/15



#### IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers who are designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only to develop an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third-party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising from your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Disclaimer Rev.1.01)

#### **Corporate Headquarters**

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

#### Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

#### **Contact Information**

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit <u>www.renesas.com/contact-us/</u>.